



SI3590DV-T1-GE3 Information



For Reference Only

Part Number SI3590DV-T1-GE3
Manufacturer Vishay Siliconix

Category Discrete Semiconductor Products
Transistors - FETs, MOSFETs - Arrays

Description MOSFET N/P-CH 30V 2.5A 6-TSOP

Package SOT-23-6 Thin, TSOT-23-6

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI3590DV-T1-GE3 Specifications

Manufacturer Part Number	SI3590DV-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	N and P-Channel
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	2.5A, 1.7A
Rds On (Max) @ Id, Vgs	77 mOhm @ 3A, 4.5V
Vgs(th) (Max) @ Id	1.5V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	4.5nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	830mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-23-6 Thin, TSOT-23-6
Supplier Device Package	6-TSOP
	Report errors?

SI3590DV-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3590DV-T1-GE3 Payment Methods



















SI3590DV-T1-GE3 Shipping Methods













If you have any question about SI3590DV-T1-GE3, please do not hesitate to contact us!

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